



PDA143X/123J/143Z/114YQA series

50 V, 100 mA PNP resistor-equipped transistors

Rev. 1 — 30 October 2015

Product data sheet

1. Product profile

1.1 General description

100 mA PNP Resistor-Equipped Transistor (RET) family in a leadless ultra small DFN1010D-3 (SOT1215) Surface-Mounted Device (SMD) plastic package with visible and solderable side pads.

Table 1. Product overview

Type number	R1	R2	Package Nexperia	NPN complement
PDA143XQA	4.7 k Ω	10 k Ω	DFN1010D-3 (SOT1215)	PDTC143XQA
PDA123JQA	2.2 k Ω	47 k Ω		PDTC123JQA
PDA143ZQA	4.7 k Ω	47 k Ω		PDTC143ZQA
PDA114YQA	10 k Ω	47 k Ω		PDTC114YQA

1.2 Features and benefits

- 100 mA output current capability
- Built-in bias resistors
- Simplifies circuit design
- Reduces component count
- Reduced pick and place costs
- Low package height of 0.37 mm
- AEC-Q101 qualified
- Suitable for Automatic Optical Inspection (AOI) of solder joint

1.3 Applications

- Digital applications
- Cost saving alternative for BC847/BC857 series in digital applications
- Controlling IC inputs
- Switching loads

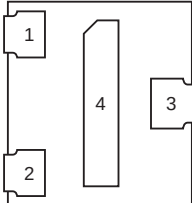
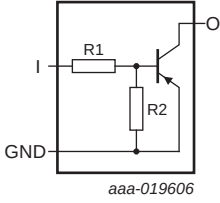
1.4 Quick reference data

Table 2. Quick reference data

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
V_{CEO}	collector-emitter voltage	open base	-	-	-50	V
I_O	output current		-	-	-100	mA

2. Pinning information

Table 3. Pinning

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	I	input (base)	 Transparent top view	 aaa-019606
2	GND	GND (emitter)		
3	O	output (collector)		
4	O	output (collector)		

3. Ordering information

Table 4. Ordering information

Type number	Package		
	Name	Description	Version
PDTA143XQA	DFN1010D-3	plastic thermal enhanced ultra thin small outline package; no leads; 3 terminals; body: 1.1 × 1.0 × 0.37 mm	SOT1215
PDTA123JQA			
PDTA143ZQA			
PDTA114YQA			

4. Marking

Table 5. Marking codes

Type number	Marking code
PDTA143XQA	11 11 10
PDTA123JQA	11 00 01
PDTA143ZQA	11 01 01
PDTA114YQA	11 10 11

4.1 Binary marking code description

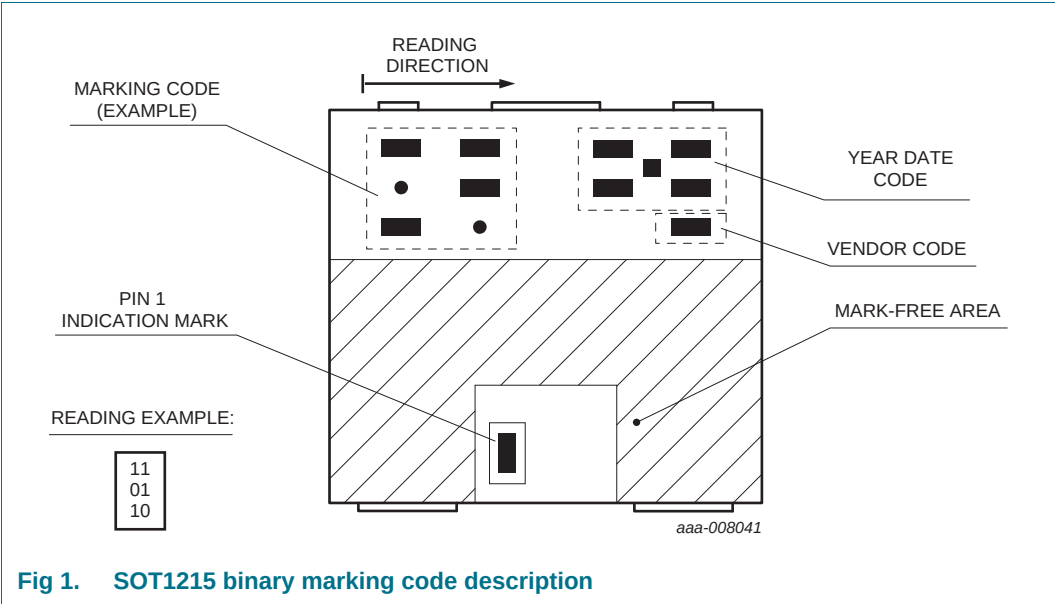


Fig 1. SOT1215 binary marking code description

5. Limiting values

Table 6. Limiting values

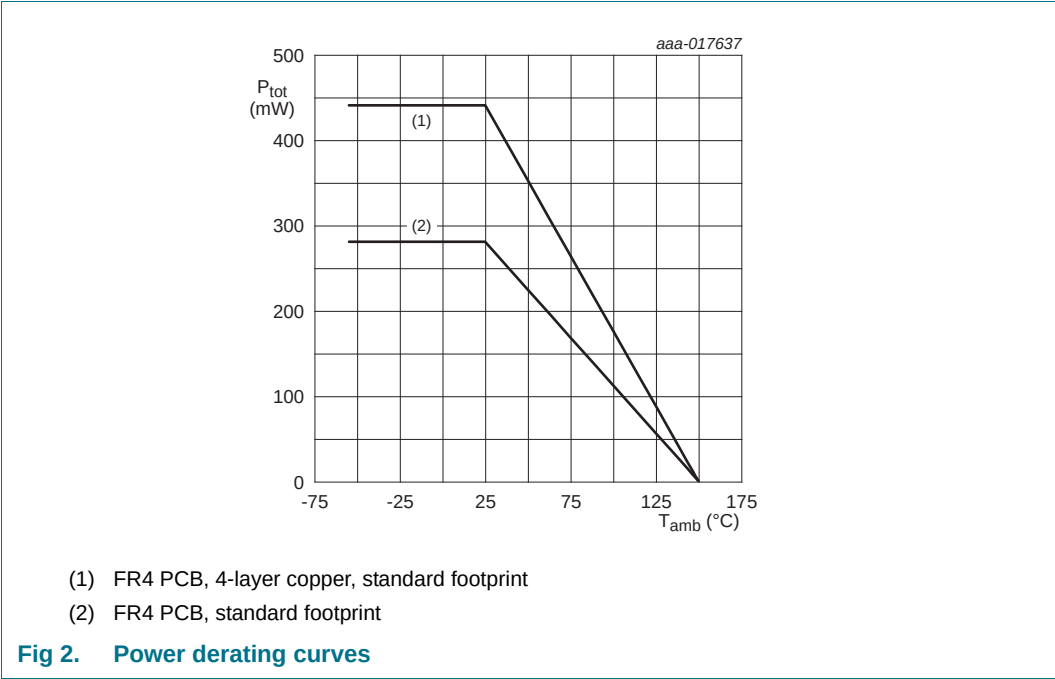
In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V _{CBO}	collector-base voltage	open emitter	-	-50	V
V _{CEO}	collector-emitter voltage	open base	-	-50	V
V _{EBO}	emitter-base voltage				
	PDTA143XQA		-	-7	V
	PDTA123JQA		-	-5	V
	PDTA143ZQA		-	-5	V
	PDTA114YQA		-	-6	V

Table 6. Limiting values ...continued
In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V _I	input voltage				
	PDTA143XQA		−30	+7	V
	PDTA123JQA		−12	+5	V
	PDTA143ZQA		−30	+5	V
	PDTA114YQA		−40	+6	V
I _O	output current		−	−100	mA
P _{tot}	total power dissipation	T _{amb} ≤ 25 °C	[1]	280	mW
			[2]	440	mW
T _j	junction temperature		−	150	°C
T _{amb}	ambient temperature		−55	+150	°C
T _{stg}	storage temperature		−65	+150	°C

- [1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.
- [2] Device mounted on an FR4 PCB, 4-layer copper, tin-plated and standard footprint.

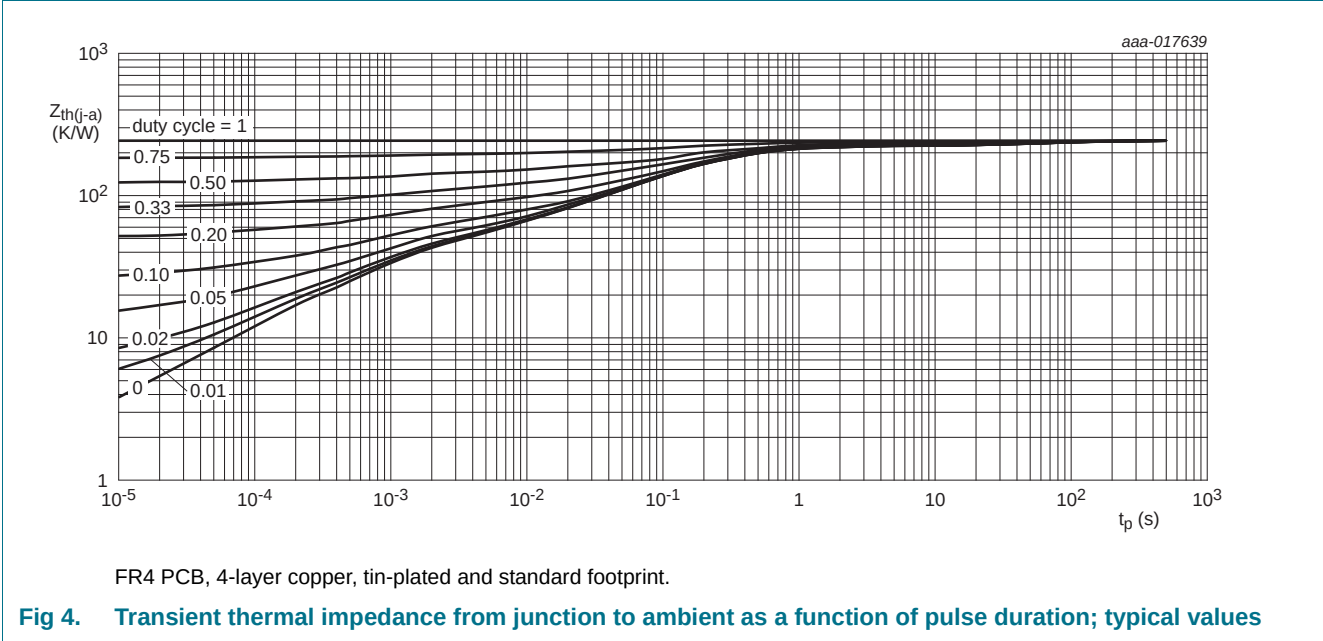
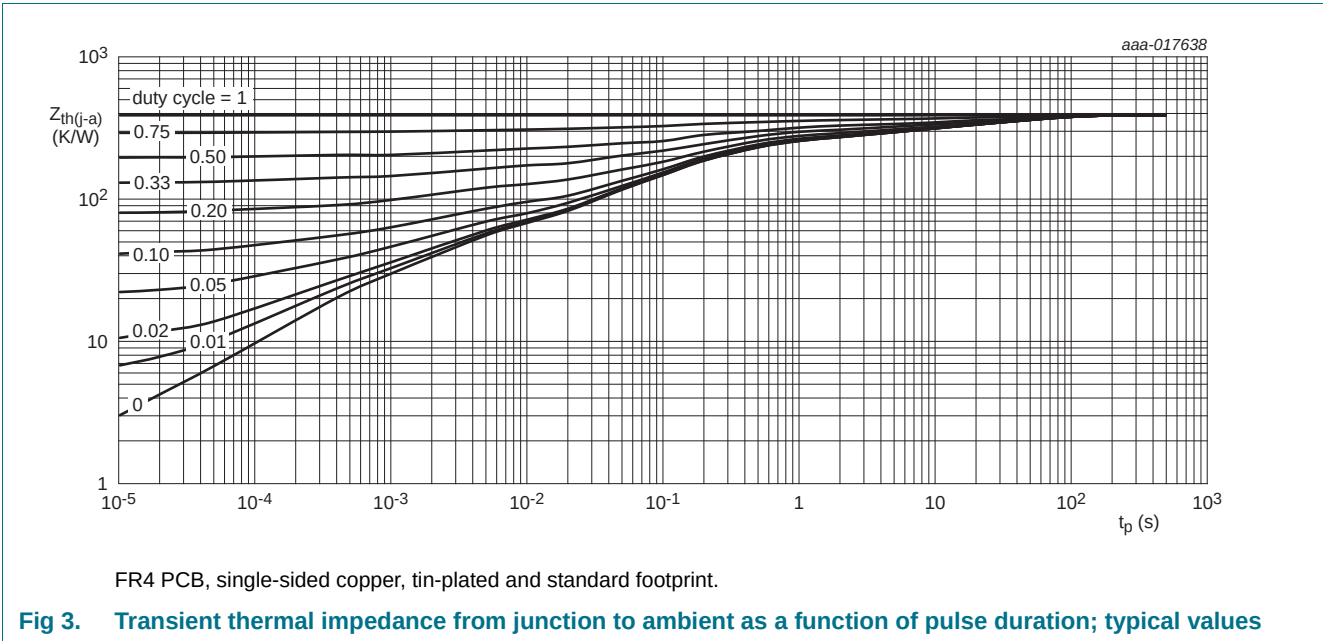


6. Thermal characteristics

Table 7. Thermal characteristics

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air	[1]	-	446	K/W
			[2]	-	284	K/W

- [1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.
[2] Device mounted on an FR4 PCB, 4-layer copper, tin-plated and standard footprint.



7. Characteristics

Table 8. Characteristics

$T_{amb} = 25\text{ °C}$ unless otherwise specified.

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
I_{CBO}	collector-base cut-off current	$V_{CB} = -50\text{ V}; I_E = 0\text{ A}$	-	-	-100	nA
I_{CEO}	collector-emitter cut-off current	$V_{CE} = -30\text{ V}; I_B = 0\text{ A}$	-	-	-1	μA
		$V_{CE} = -30\text{ V}; I_B = 0\text{ A}; T_j = 150\text{ °C}$	-	-	-5	μA
I_{EBO}	emitter-base cut-off current					
	PDTA143XQA	$V_{EB} = -5\text{ V}; I_C = 0\text{ A}$	-	-	-600	μA
	PDTA123JQA		-	-	-180	μA
	PDTA143ZQA		-	-	-170	μA
	PDTA114YQA		-	-	-150	μA
h_{FE}	DC current gain					
	PDTA143XQA	$V_{CE} = -5\text{ V}; I_C = -10\text{ mA}$	50	-	-	
	PDTA123JQA	$V_{CE} = -5\text{ V}; I_C = -10\text{ mA}$	100	-	-	
	PDTA143ZQA	$V_{CE} = -5\text{ V}; I_C = -10\text{ mA}$	100	-	-	
	PDTA114YQA	$V_{CE} = -5\text{ V}; I_C = -5\text{ mA}$	100	-	-	
V_{CEsat}	collector-emitter saturation voltage					
	PDTA143XQA	$I_C = -10\text{ mA}; I_B = -0.5\text{ mA}$	-	-	-100	mV
	PDTA123JQA	$I_C = -5\text{ mA}; I_B = -0.25\text{ mA}$	-	-	-100	mV
	PDTA143ZQA	$I_C = -5\text{ mA}; I_B = -0.25\text{ mA}$	-	-	-100	mV
	PDTA114YQA	$I_C = -5\text{ mA}; I_B = -0.25\text{ mA}$	-	-	-100	mV
$V_{I(off)}$	off-state input voltage					
	PDTA143XQA	$V_{CE} = -5\text{ V}; I_C = -100\text{ }\mu\text{A}$	-	-0.9	-0.3	V
	PDTA123JQA		-	-0.6	-0.5	V
	PDTA143ZQA		-	-0.6	-0.5	V
	PDTA114YQA		-	-0.7	-0.5	V
$V_{I(on)}$	on-state input voltage					
	PDTA143XQA	$V_{CE} = -0.3\text{ V}; I_C = -20\text{ mA}$	-2.5	-1.5	-	V
	PDTA123JQA	$V_{CE} = -0.3\text{ V}; I_C = -5\text{ mA}$	-1.1	-0.75	-	V
	PDTA143ZQA	$V_{CE} = -0.3\text{ V}; I_C = -5\text{ mA}$	-1.3	-0.9	-	V
	PDTA114YQA	$V_{CE} = -0.3\text{ V}; I_C = -1\text{ mA}$	-1.4	-0.8	-	V
R1	bias resistor 1 (input)	[1]				
	PDTA143XQA		3.3	4.7	6.1	k Ω
	PDTA123JQA		1.54	2.2	2.86	k Ω
	PDTA143ZQA		3.3	4.7	6.1	k Ω
	PDTA114YQA		7	10	13	k Ω

Table 8. Characteristics ...continued $T_{amb} = 25\text{ }^{\circ}\text{C}$ unless otherwise specified.

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
R2/R1	bias resistor ratio	[1]				
	PDTA143XQA		1.7	2.1	2.6	
	PDTA123JQA		17	21	26	
	PDTA143ZQA		8	10	12	
	PDTA114YQA		3.7	4.7	5.7	
C_c	collector capacitance	$V_{CB} = -10\text{ V}$; $I_E = I_E = 0\text{ A}$; $f = 1\text{ MHz}$	-	-	3	pF
f_T	transition frequency	$V_{CE} = -5\text{ V}$; $I_C = -10\text{ mA}$; $f = 100\text{ MHz}$ [2]	-	180	-	MHz

[1] See [Section 8 “Test information”](#) for resistor calculation and test conditions.

[2] Characteristics of built-in transistor.

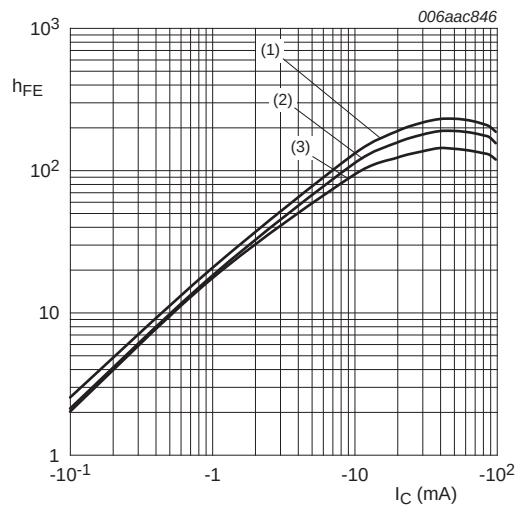


Fig 5. PDTA143XQA: DC current gain as a function of collector current; typical values

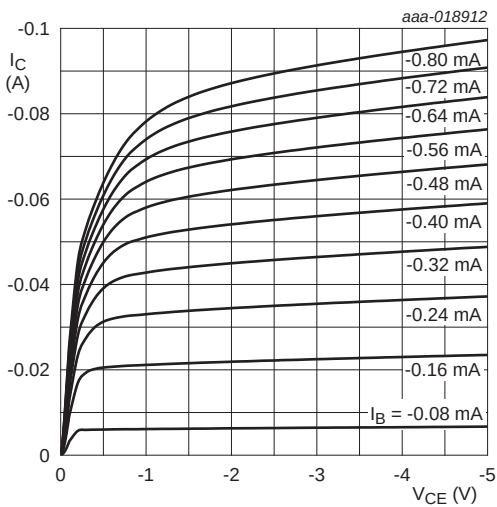


Fig 6. PDTA143XQA: Collector current as a function of collector-emitter voltage; typical values

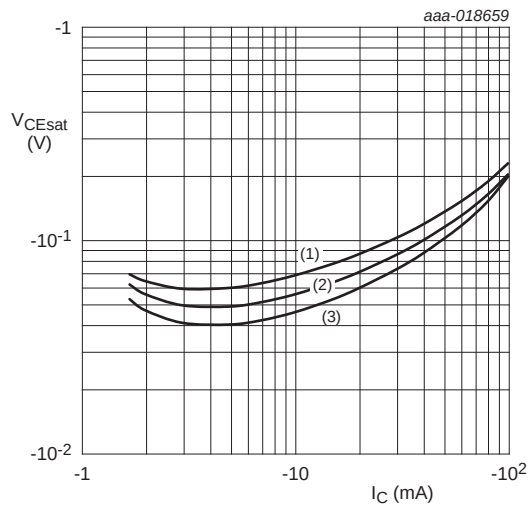


Fig 7. PDTA143XQA: Collector-emitter saturation voltage as a function of collector current; typical values

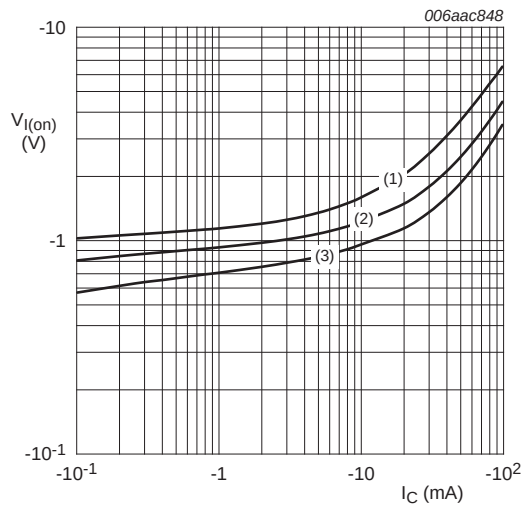
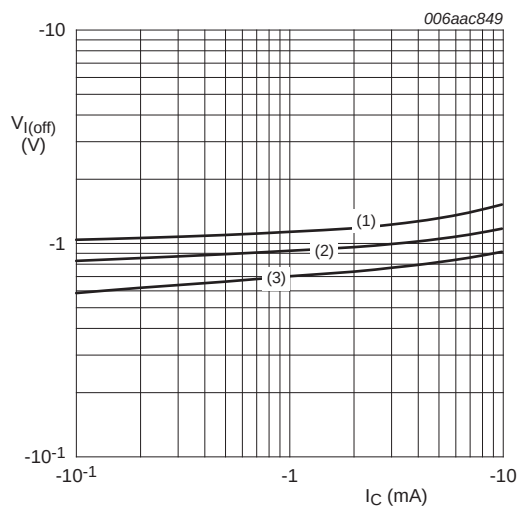
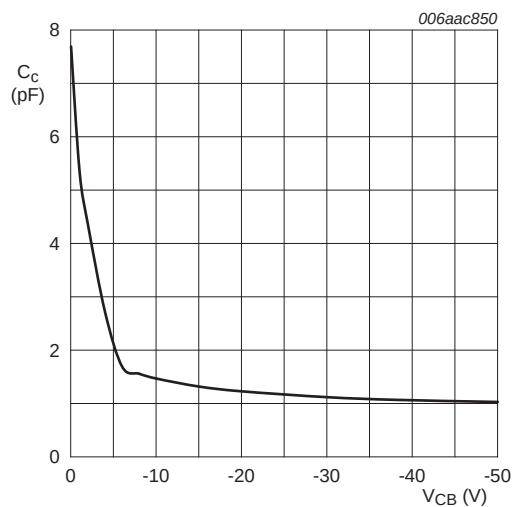


Fig 8. PDTA143XQA: On-state input voltage as a function of collector current; typical values



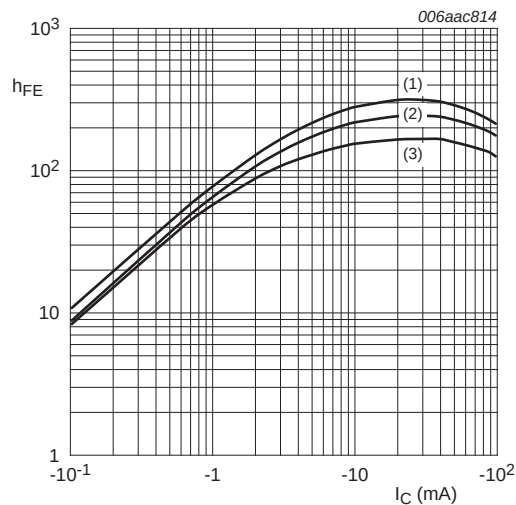
$V_{CE} = -5\text{ V}$
(1) $T_{amb} = -40^\circ\text{C}$
(2) $T_{amb} = 25^\circ\text{C}$
(3) $T_{amb} = 100^\circ\text{C}$

Fig 9. PDTA143XQA: Off-state input voltage as a function of collector current; typical values



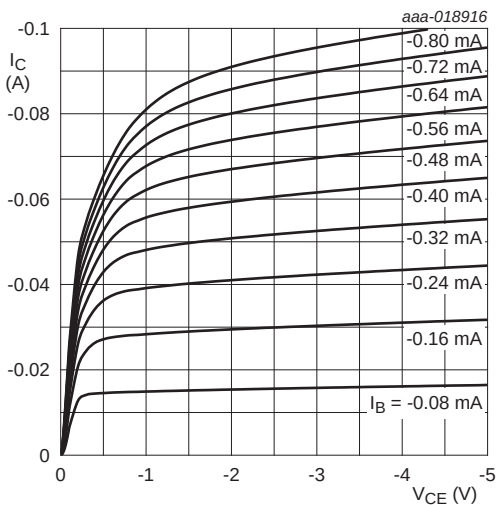
$f = 1\text{ MHz}; T_{amb} = 25^\circ\text{C}$

Fig 10. PDTA143XQA: Collector capacitance as a function of collector-base voltage; typical values



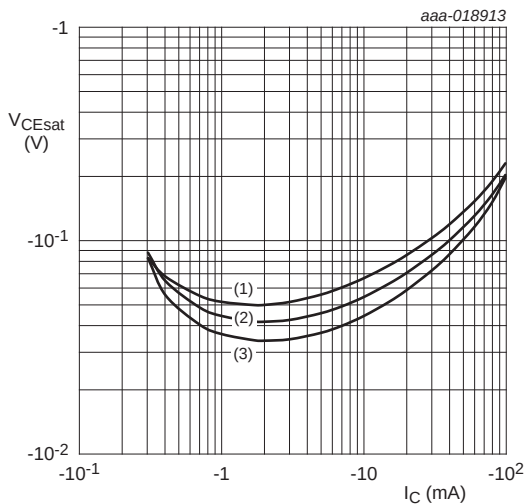
$V_{CE} = -5\text{ V}$
(1) $T_{amb} = 100\text{ }^{\circ}\text{C}$
(2) $T_{amb} = 25\text{ }^{\circ}\text{C}$
(3) $T_{amb} = -40\text{ }^{\circ}\text{C}$

Fig 11. PDTA123JQA: DC current gain as a function of collector current; typical values



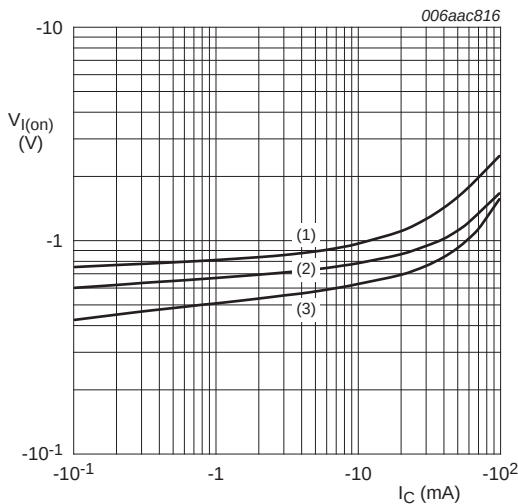
$T_{amb} = 25\text{ }^{\circ}\text{C}$

Fig 12. PDTA123JQA: Collector current as a function of collector-emitter voltage; typical values



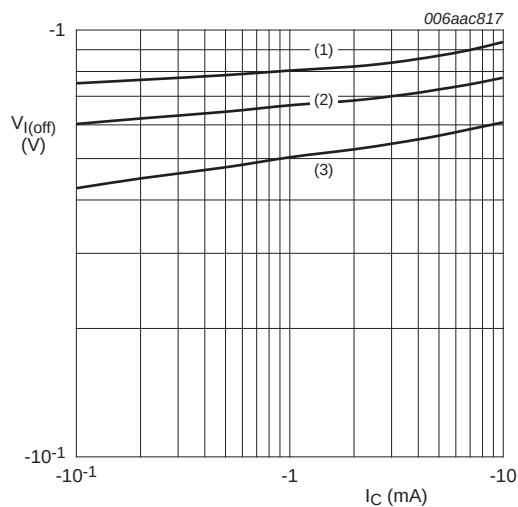
$I_C/I_B = 20$
(1) $T_{amb} = 100\text{ }^{\circ}\text{C}$
(2) $T_{amb} = 25\text{ }^{\circ}\text{C}$
(3) $T_{amb} = -40\text{ }^{\circ}\text{C}$

Fig 13. PDTA123JQA: Collector-emitter saturation voltage as a function of collector current; typical values



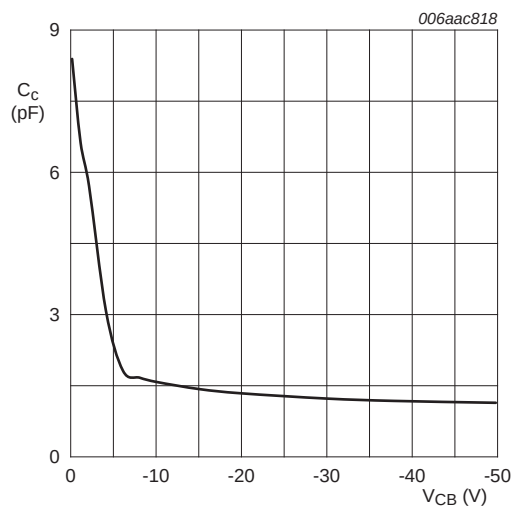
$V_{CE} = -0.3\text{ V}$
(1) $T_{amb} = -40\text{ }^{\circ}\text{C}$
(2) $T_{amb} = 25\text{ }^{\circ}\text{C}$
(3) $T_{amb} = 100\text{ }^{\circ}\text{C}$

Fig 14. PDTA123JQA: On-state input voltage as a function of collector current; typical values



- $V_{CE} = -5$ V
- (1) $T_{amb} = -40$ °C
 - (2) $T_{amb} = 25$ °C
 - (3) $T_{amb} = 100$ °C

Fig 15. PDTA123JQA: Off-state input voltage as a function of collector current; typical values



$f = 1$ MHz; $T_{amb} = 25$ °C

Fig 16. PDTA123JQA: Collector capacitance as a function of collector-base voltage; typical values

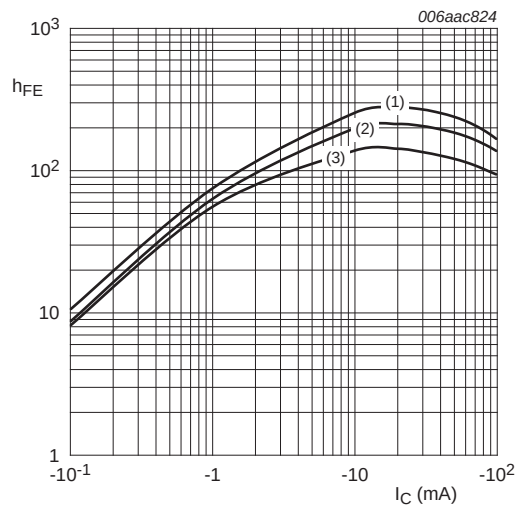


Fig 17. PDTA143ZQA: DC current gain as a function of collector current; typical values

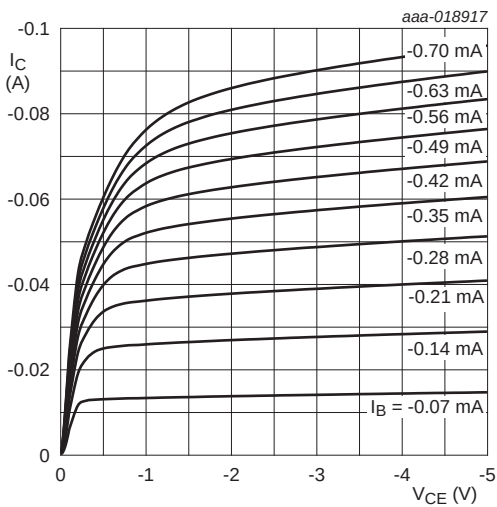


Fig 18. PDTA143ZQA: Collector current as a function of collector-emitter voltage; typical values

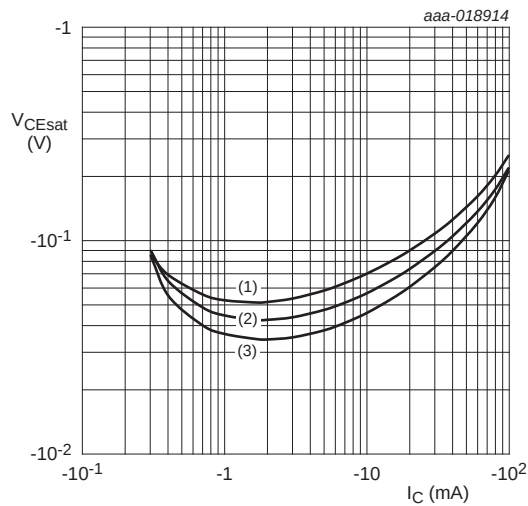


Fig 19. PDTA143ZQA: Collector-emitter saturation voltage as a function of collector current; typical values

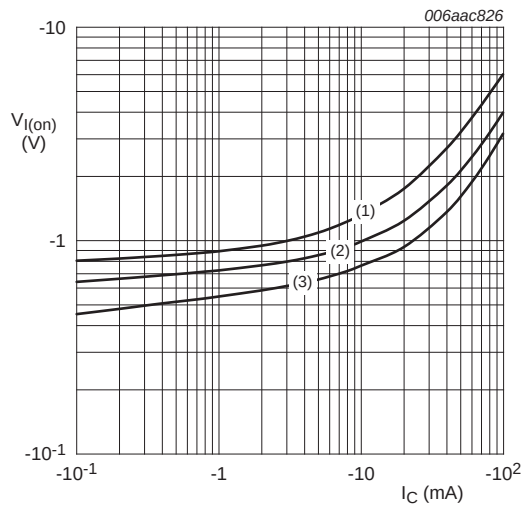
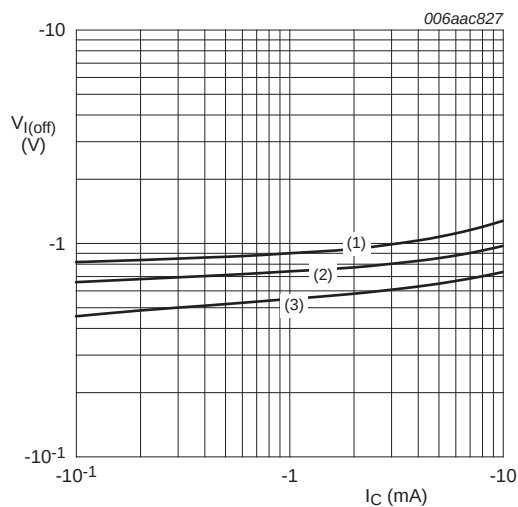
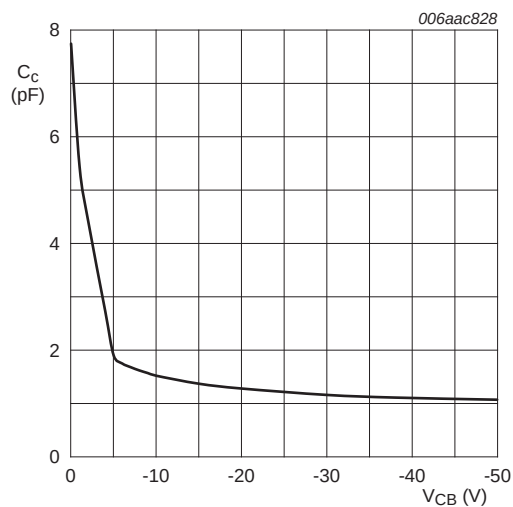


Fig 20. PDTA143ZQA: On-state input voltage as a function of collector current; typical values



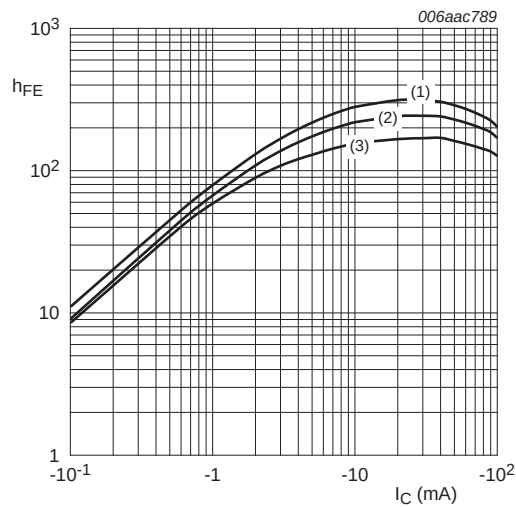
$V_{CE} = -5\text{ V}$
(1) $T_{amb} = -40^\circ\text{C}$
(2) $T_{amb} = 25^\circ\text{C}$
(3) $T_{amb} = 100^\circ\text{C}$

Fig 21. PDTA143ZQA: Off-state input voltage as a function of collector current; typical values



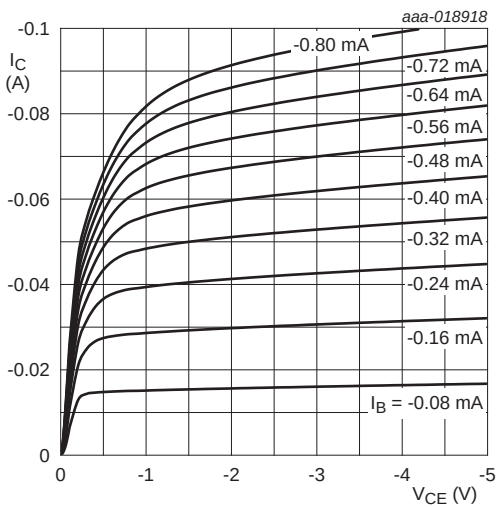
$f = 1\text{ MHz}; T_{amb} = 25^\circ\text{C}$

Fig 22. PDTA143ZQA: Collector capacitance as a function of collector-base voltage; typical values



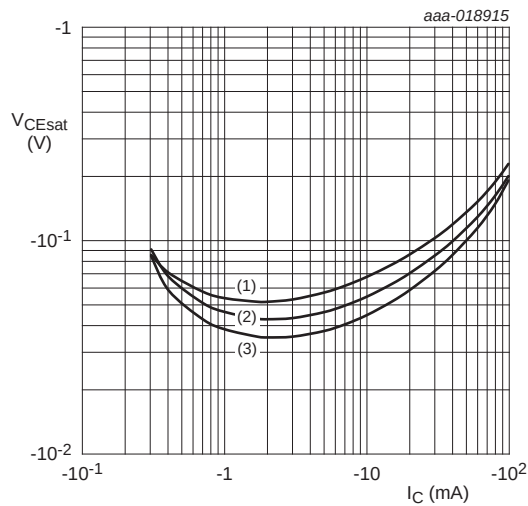
$V_{CE} = -5\text{ V}$
(1) $T_{amb} = 100^\circ\text{C}$
(2) $T_{amb} = 25^\circ\text{C}$
(3) $T_{amb} = -40^\circ\text{C}$

Fig 23. PDTA114YQA: DC current gain as a function of collector current; typical values



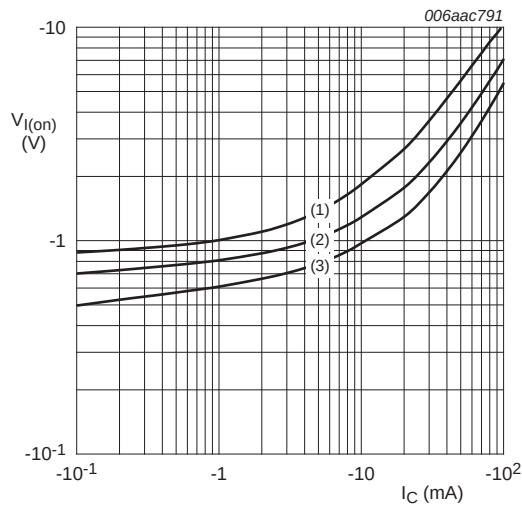
$T_{amb} = 25^\circ\text{C}$

Fig 24. PDTA114YQA: Collector current as a function of collector-emitter voltage; typical values



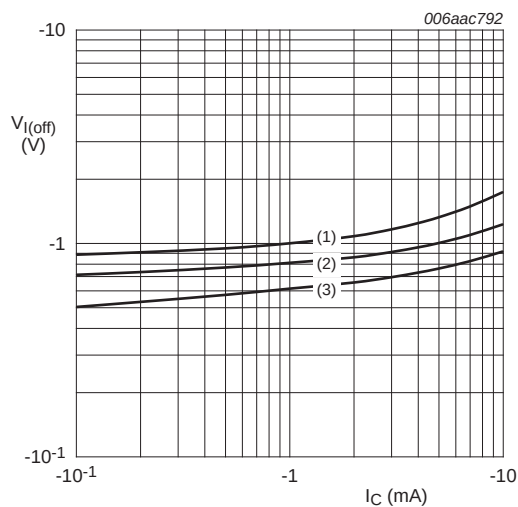
$I_C/I_B = 20$
(1) $T_{amb} = 100^\circ\text{C}$
(2) $T_{amb} = 25^\circ\text{C}$
(3) $T_{amb} = -40^\circ\text{C}$

Fig 25. PDTA114YQA: Collector-emitter saturation voltage as a function of collector current; typical values



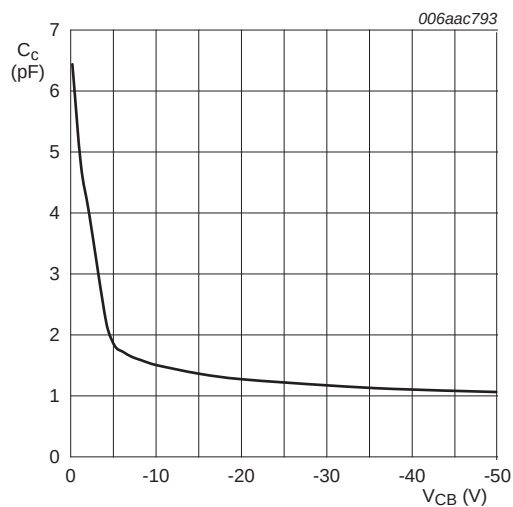
$V_{CE} = -0.3\text{ V}$
(1) $T_{amb} = -40^\circ\text{C}$
(2) $T_{amb} = 25^\circ\text{C}$
(3) $T_{amb} = 100^\circ\text{C}$

Fig 26. PDTA114YQA: On-state input voltage as a function of collector current; typical values



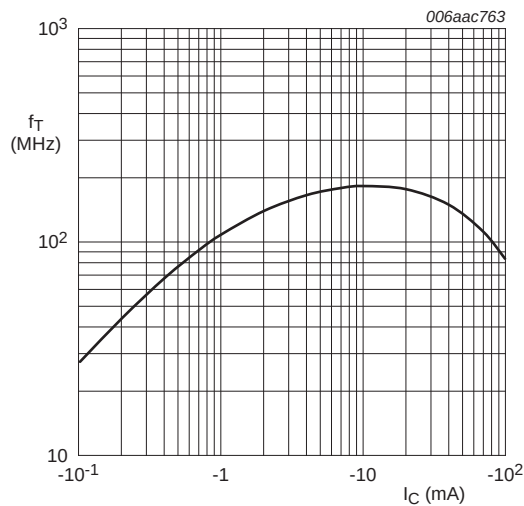
- $V_{CE} = -5\text{ V}$
- (1) $T_{amb} = -40\text{ }^{\circ}\text{C}$
 - (2) $T_{amb} = 25\text{ }^{\circ}\text{C}$
 - (3) $T_{amb} = 100\text{ }^{\circ}\text{C}$

Fig 27. PDTA114YQA: Off-state input voltage as a function of collector current; typical values



$f = 1\text{ MHz}$; $T_{amb} = 25\text{ }^{\circ}\text{C}$

Fig 28. PDTA114YQA: Collector capacitance as a function of collector-base voltage; typical values



$V_{CE} = -5\text{ V}$; $T_{amb} = 25\text{ }^{\circ}\text{C}$

Fig 29. Transition frequency as a function of collector current; typical values of built-in transistor

8. Test information

8.1 Quality information

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard *Q101 - Stress test qualification for discrete semiconductors*, and is suitable for use in automotive applications.

8.2 Resistor calculation

- Calculation of bias resistor 1 (R1):

$$R1 = \frac{V(I_{I2}) - V(I_{I1})}{I_{I2} - I_{I1}}$$

- Calculation of bias resistor ratio (R2/R1):

$$\frac{R2}{R1} = \frac{V(I_{I4}) - V(I_{I3})}{R1 \cdot (I_{I4} - I_{I3})} - 1$$

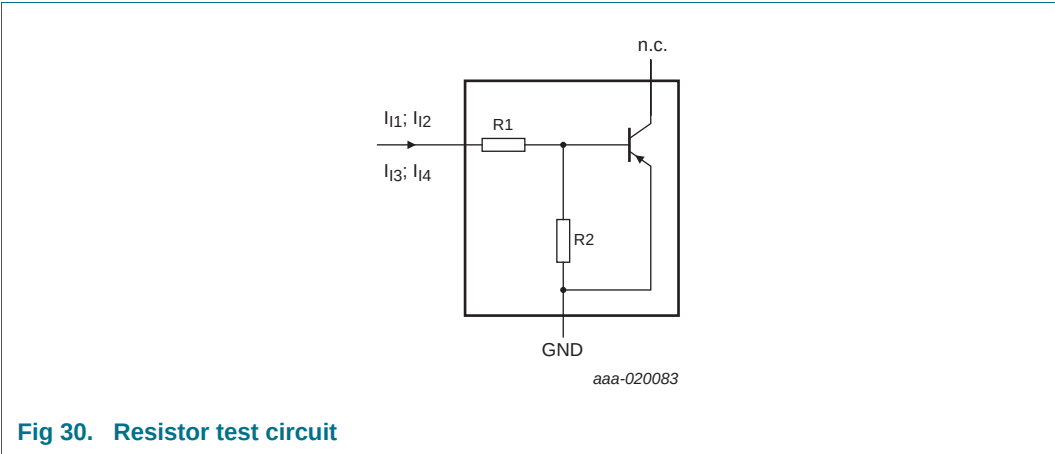


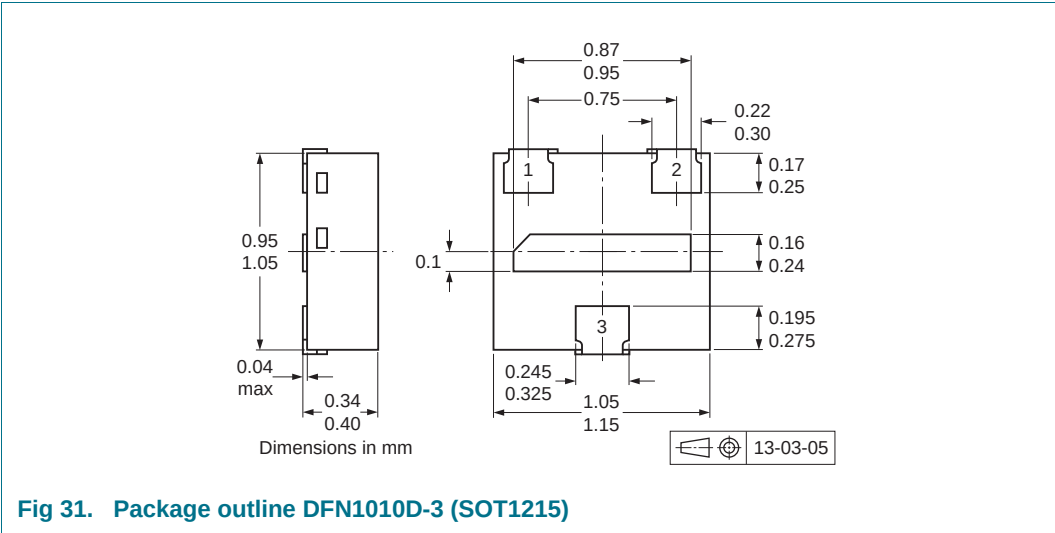
Fig 30. Resistor test circuit

8.3 Resistor test conditions

Table 9. Resistor test conditions

Type number	R1 (kΩ)	R2 (kΩ)	Test conditions			
			I _{I1}	I _{I2}	I _{I3}	I _{I4}
PDTA143XQA	4.7	10	−350 μA	−450 μA	350 μA	450 μA
PDTA123JQA	2.2	47	−90 μA	−140 μA	55 μA	105 μA
PDTA143ZQA	4.7	47	−90 μA	−140 μA	55 μA	105 μA
PDTA114YQA	10	47	−90 μA	−140 μA	55 μA	105 μA

9. Package outline



10. Soldering

Footprint information for reflow soldering of DFN1010D-3 package

SOT1215

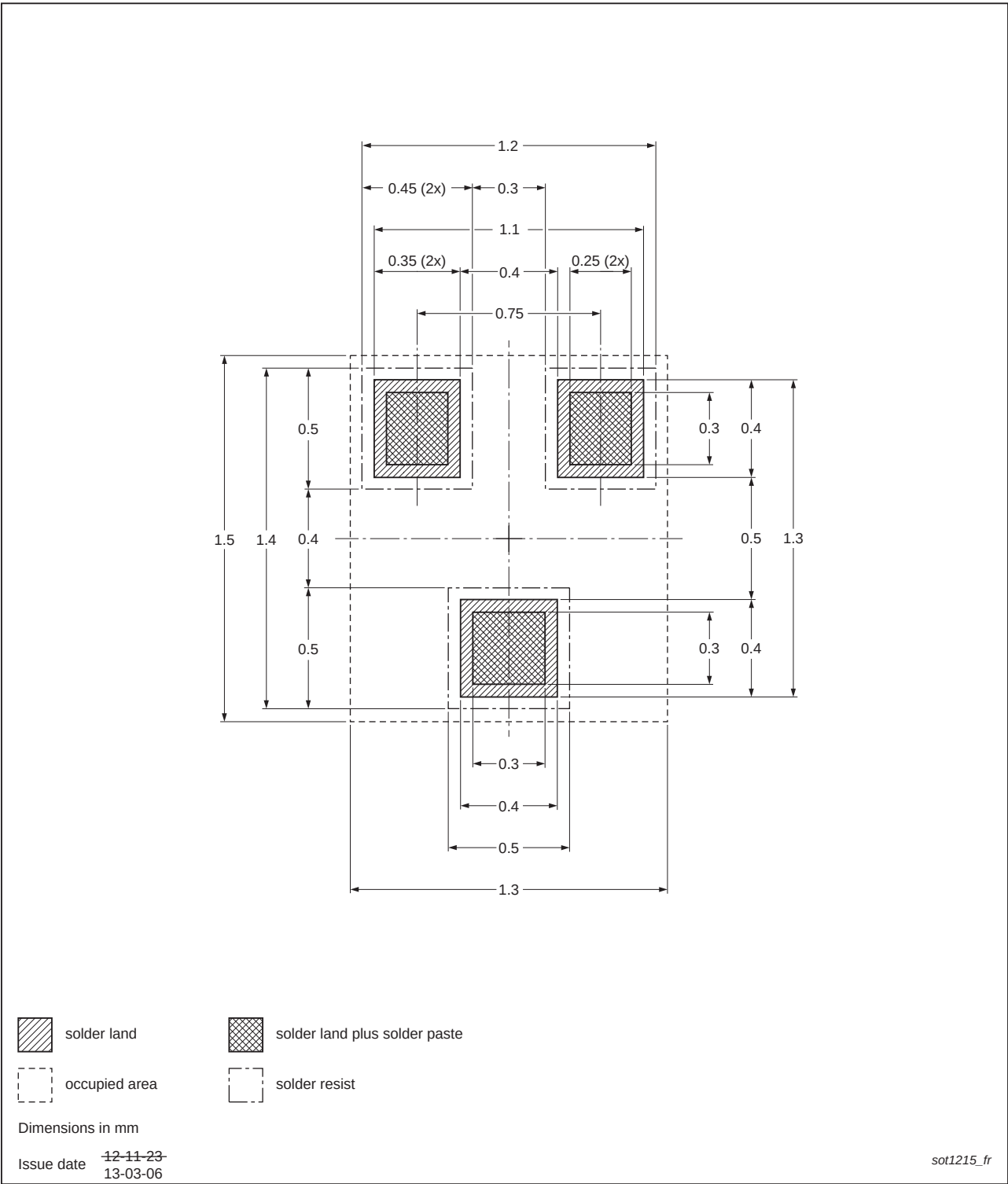


Fig 32. Reflow soldering footprint DFN1010D-3 (SOT1215)

11. Revision history

Table 10. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
PDTA143X_123J_143Z_114YQA_SER v.1	20151030	Product data sheet	-	-

12. Legal information

12.1 Data sheet status

Document status ^{[1][2]}	Product status ^[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

[3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL <http://www.nexperia.com>.

12.2 Definitions

Draft — The document is a draft version only. The content is still under internal review and subject to formal approval, which may result in modifications or additions. Nexperia does not give any representations or warranties as to the accuracy or completeness of information included herein and shall have no liability for the consequences of use of such information.

Short data sheet — A short data sheet is an extract from a full data sheet with the same product type number(s) and title. A short data sheet is intended for quick reference only and should not be relied upon to contain detailed and full information. For detailed and full information see the relevant full data sheet, which is available on request via the local Nexperia sales office. In case of any inconsistency or conflict with the short data sheet, the full data sheet shall prevail.

Product specification — The information and data provided in a Product data sheet shall define the specification of the product as agreed between Nexperia and its customer, unless Nexperia and customer have explicitly agreed otherwise in writing. In no event however, shall an agreement be valid in which the Nexperia product is deemed to offer functions and qualities beyond those described in the Product data sheet.

12.3 Disclaimers

Limited warranty and liability — Information in this document is believed to be accurate and reliable. However, Nexperia does not give any representations or warranties, expressed or implied, as to the accuracy or completeness of such information and shall have no liability for the consequences of use of such information. Nexperia takes no responsibility for the content in this document if provided by an information source outside of Nexperia.

In no event shall Nexperia be liable for any indirect, incidental, punitive, special or consequential damages (including - without limitation - lost profits, lost savings, business interruption, costs related to the removal or replacement of any products or rework charges) whether or not such damages are based on tort (including negligence), warranty, breach of contract or any other legal theory.

Notwithstanding any damages that customer might incur for any reason whatsoever, Nexperia's aggregate and cumulative liability towards customer for the products described herein shall be limited in accordance with the *Terms and conditions of commercial sale* of Nexperia.

Right to make changes — Nexperia reserves the right to make changes to information published in this document, including without limitation specifications and product descriptions, at any time and without notice. This document supersedes and replaces all information supplied prior to the publication hereof.

Suitability for use in automotive applications — This Nexperia product has been qualified for use in automotive applications. Unless otherwise agreed in writing, the product is not designed, authorized or warranted to be suitable for use in life support, life-critical or safety-critical systems or equipment, nor in applications where failure or malfunction of a Nexperia product can reasonably be expected to result in personal injury, death or severe property or environmental damage. Nexperia and its suppliers accept no liability for inclusion and/or use of Nexperia products in such equipment or applications and therefore such inclusion and/or use is at the customer's own risk.

Applications — Applications that are described herein for any of these products are for illustrative purposes only. Nexperia makes no representation or warranty that such applications will be suitable for the specified use without further testing or modification.

Customers are responsible for the design and operation of their applications and products using Nexperia products, and Nexperia accepts no liability for any assistance with applications or customer product design. It is customer's sole responsibility to determine whether the Nexperia product is suitable and fit for the customer's applications and products planned, as well as for the planned application and use of customer's third party customer(s). Customers should provide appropriate design and operating safeguards to minimize the risks associated with their applications and products.

Nexperia does not accept any liability related to any default, damage, costs or problem which is based on any weakness or default in the customer's applications or products, or the application or use by customer's third party customer(s). Customer is responsible for doing all necessary testing for the customer's applications and products using Nexperia products in order to avoid a default of the applications and the products or of the application or use by customer's third party customer(s). Nexperia does not accept any liability in this respect.

Limiting values — Stress above one or more limiting values (as defined in the Absolute Maximum Ratings System of IEC 60134) will cause permanent damage to the device. Limiting values are stress ratings only and (proper) operation of the device at these or any other conditions above those given in the Recommended operating conditions section (if present) or the Characteristics sections of this document is not warranted. Constant or repeated exposure to limiting values will permanently and irreversibly affect the quality and reliability of the device.

Terms and conditions of commercial sale — Nexperia products are sold subject to the general terms and conditions of commercial sale, as published at <http://www.nexperia.com/profile/terms>, unless otherwise agreed in a valid written individual agreement. In case an individual agreement is concluded only the terms and conditions of the respective agreement shall apply. Nexperia hereby expressly objects to applying the customer's general terms and conditions with regard to the purchase of Nexperia products by customer.

No offer to sell or license — Nothing in this document may be interpreted or construed as an offer to sell products that is open for acceptance or the grant, conveyance or implication of any license under any copyrights, patents or other industrial or intellectual property rights.

Export control — This document as well as the item(s) described herein may be subject to export control regulations. Export might require a prior authorization from competent authorities.

Quick reference data — The Quick reference data is an extract of the product data given in the Limiting values and Characteristics sections of this document, and as such is not complete, exhaustive or legally binding.

Translations — A non-English (translated) version of a document is for reference only. The English version shall prevail in case of any discrepancy between the translated and English versions.

12.4 Trademarks

Notice: All referenced brands, product names, service names and trademarks are the property of their respective owners.

13. Contact information

For more information, please visit: <http://www.nexperia.com>

For sales office addresses, please send an email to: salesaddresses@nexperia.com

14. Contents

1	Product profile	1
1.1	General description	1
1.2	Features and benefits	1
1.3	Applications	1
1.4	Quick reference data	1
2	Pinning information	2
3	Ordering information	2
4	Marking	3
4.1	Binary marking code description	3
5	Limiting values	3
6	Thermal characteristics	5
7	Characteristics	6
8	Test information	16
8.1	Quality information	16
8.2	Resistor calculation	16
8.3	Resistor test conditions	16
9	Package outline	17
10	Soldering	18
11	Revision history	19
12	Legal information	20
12.1	Data sheet status	20
12.2	Definitions	20
12.3	Disclaimers	20
12.4	Trademarks	21
13	Contact information	21
14	Contents	22